

# **SD103A - SD103C**

### **Features**

- Low Forward Voltage Drop
- **Guard Ring Construction for Transient Protection**
- Low Reverse Recovery Time
- Low Reverse Capacitance
- Lead Free Finish, RoHS Compliant (Note 2)

#### **Mechanical Data**

Case: DO-35

Case Material: Glass

Moisture Sensitivity: Level 1 per J-STD-020C

Leads: Solderable per MIL-STD-202, Method

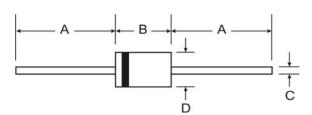
Terminals: Finish — Sn96.5Ag3.5. Solderable per MIL-STD-202, Method 208 @3

Polarity: Cathode Band

Marking Information: See Page 3

Ordering Information: See Page 3

Weight: 0.13 grams (approximate)



DO-35				
Dim	Min	Max		
Α	25.40	_		
В	_	4.00		
С	_	0.60		
D	_	2.00		
All Dimensions in mm				

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	SD103A	SD103B	SD103C	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$				
Working Peak Reverse Voltage	$V_{RWM}$	40	30	20	V
DC Blocking Voltage	$V_R$				
RMS Reverse Voltage	$V_{R(RMS)}$	28	21	14	V
Forward Continuous Current	I <sub>FM</sub>		350		mA
Repetitive Peak Forward Current (Note 1) @ t ≤ 1.0s	I <sub>FRM</sub>		1.0		Α
Non-Repetitive Peak Forward Surge Current 8.3 ms Half Sine Wave	I <sub>FSM</sub>		15		Α
Power Dissipation (Note 1)	$P_d$		400		mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$		300		°C/W
Operating Junction Temperature	T <sub>i</sub>		125		°C
Storage Temperature Range	T <sub>STG</sub>		-55 to +150		°C

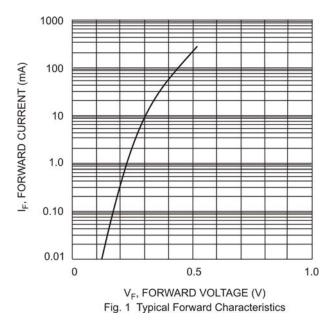
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

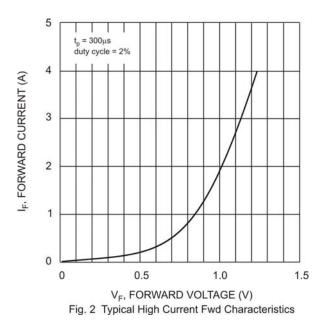
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	SD103A SD103B SD103C	$V_{(BR)R}$	40 30 20	_	_	V	$I_R = 100 \mu A$
Maximum Forward Voltage Drop		$V_{FM}$	_	_	0.37 0.60	V	$I_F = 20 \text{mA}$ $I_F = 200 \text{mA}$
Maximum Peak Reverse Current (Note 3)	SD103A SD103B SD103C	I <sub>RM</sub>			5.0	μА	$V_R = 30V$ $V_R = 20V$ $V_R = 10V$
Total Capacitance		C <sub>T</sub>		50	_	pF	$V_R = 0V, f = 1.0MHz$
Reverse Recovery Time		t <sub>rr</sub>		10	_	ns	$I_F = I_R = 50 \text{mA} \text{ to } 200 \text{mA},$ $I_{rr} = 0.1 \text{ x } I_R, R_L = 100 \Omega$

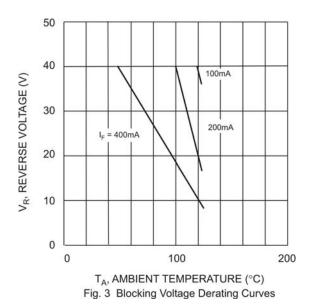
Notes:

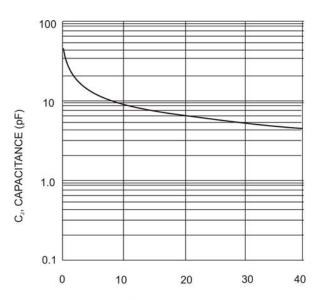
- 1. Valid provided that device terminals are kept at ambient temperature.
- 2. EC Directive 2002/95/EC (RoHS) revision 13.2.2003. Glass and high temperature solder exemptions applied where applicable, see EU Directive Annex Notes 5 and 7.
- 3. Short duration test pulse used to minimize self-heating effect.











V<sub>R</sub>, REVERSE VOLTAGE (V) Fig. 4 Typ. Junction Capacitance vs Reverse Voltage

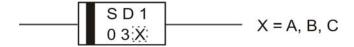


# Ordering Information (Note 4)

Device	Packaging	Shipping
SD103A-A	DO-35	10,000 / Ammo Pak
SD103A-T	DO-35	10,000 / Tape & Reel
SD103B-A	DO-35	10,000 / Ammo Pak
SD103B-T	DO-35	10,000 / Tape & Reel
SD103C-A	DO-35	10,000 / Ammo Pak
SD103C-T	DO-35	10,000 / Tape & Reel

4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



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